

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S120	16	stephan near2 mueller.in. and (sic or silicon near2 carbide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 13:55
S125	17	stephan near2 mueller.in. and (sic or silicon near2 carbide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 13:57
S128	154	(sic or silicon near2 carbide) same pattern\$6 same lateral	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 13:58
S127	3	stephan near2 mueller.in. and stick\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 13:58
S126	9	stephan near2 mueller.in. and pattern\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 13:58
S124	149	pattern\$4 same (sic or silicon adj carbide) and "117"/\$4.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:44
L1	150	pattern\$4 same (sic or silicon adj carbide) and "117"/\$4.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:44
S118	20	(sic or silicon near2 carbide) near15 mask\$5 near14 grow\$6 near5 selectiv\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:45
S117	128	(sic or silicon near2 carbide) near15 mask\$5 near14 grow\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:45

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S11 1	3	(sic or silicon near2 carbide) near15 lateral\$6 near15 side\$5 same (crystal\$6 near2 single or monocystal\$7)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:45
L2	21	(sic or silicon near2 carbide) near15 mask\$5 near14 grow\$6 near5 selectiv\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:45
L4	3	(sic or silicon near2 carbide) near15 lateral\$6 near15 side\$5 same (crystal\$6 near2 single or monocystal\$7)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:46
L3	131	(sic or silicon near2 carbide) near15 mask\$5 near14 grow\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:46
S6	10	(Sic or silicon adj carbide) same seed same (pattern\$4 or selectiv\$4) and "117"/\$4.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:56
L5	28	(Sic or silicon adj carbide) same seed same (pattern\$4 or selectiv\$4) and "117"/\$4.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 14:56
S79	25	single near2 crystal\$5 near5 (sic or silicon near2 carbide) same (pvt physical near2 vapor near2 transport\$5 or sublimat\$5) and lateral near2 (grow\$4 or overgrow\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 15:02
L6	26	single near2 crystal\$5 near5 (sic or silicon near2 carbide) same (pvt physical near2 vapor near2 transport\$5 or sublimat\$5) and lateral near2 (grow\$4 or overgrow\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/05 15:02